502191205 01/10/2013

PATENT ASSIGNMENT

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
Chien-Ting Lin	11/19/2012
Shih-Hung Tsai	01/03/2013

RECEIVING PARTY DATA

Name:	UNITED MICROELECTRONICS CORP.
Street Address:	No.3, Li-Hsin Road 2, Science-Based Industrial Park
City:	Hsin-Chu City
State/Country:	TAIWAN

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	13738934

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	ATTORNEY DOCKET NUMBER:	NAUP1558USA
- 1		

NAME OF SUBMITTER:	∥ SIBYL YU

Total Attachments: 4

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PATENT REEL: 029608 FRAME: 0378 l \$40.00 1373893

COMBINE DECLARATION (37 CFR 1.63) FOR UTILITY OR DESIGN APPLICATION USING AN APPLICATION DATA SHEET (37 CFR 1.76) AND ASSIGNMENT

Title of Invention:

COMPLEMENTARY METAL OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTOR, METAL OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTOR AND MANUFACTURING METHOD THEREOF

As the below named inventor, I here This declaration is directed to:	by declare that:			
☑ The attached application, or				
☐ United States application number		filed	l on	, or
☐ PCT international applicatio	n number	fi	iled on	
The above-identified application was	made or authorized	d to be made by me	€.	
I believe that I am the original invent application.	or or an original joir	it inventor of a clain	ned invention in	the
I hereby acknowledge that any willfu under18 U.S.C. 1001 by fine or impr				•
In consideration of the payment by	UNITED MICRO	ELECTRONICS	having a pos	stal address of
No.3, Li-Hsin Road 2, Science	-Based Industri	al Park, Hsin-Ch	ոս City 300, T	aiwan, R.O.C
(referred to as "ASSIGNEE"below) to acknowledged, andfor other good ar			e receipt of whic	ch is hereby
I hereby sell, assign and transfer to a the entire right, title and interest in a invention as above-identified applica- invention by the above application of substitutes, or extensions thereof, an	nd to any and all im tion and, in and to, r any continuations,	provements which a all Letters Patent to continuation-in-par	are disclosed in be obtained for t, divisions, rene	the r said ewals,
I hereby covenant that no assignment entered into which would conflict with		or encumbrance ha	as been or will be	e made or
I further covenant that ASSIGNEE wand documents relating to said inverknown and accessible to I and will terelated thereto and will promptly exe	ntion and said Lette estify as to the same	rs Patent and legal in any interference	equivalents as r e, litigation proce	may be
representatives any and all papers, i maintain, issue and enforce said app equivalents thereof which may be no IN WINTNESS WHEREOF, I have h	olication, said invent ecessary or desirable	tion and said Letters e to carry out the p	s Patent and sai roposes thereof.	
Note: An application data sheet (PTC				

Page 1 of 4

F#NPO-P0002E-US1201 DSC0-101U014318

Docket No NAUP1558USA

LEGAL NAME OF INVENTOR(ASSIGNOR)

inventor:

Chien-Ting Lin

Date

te: (100,19 701)

Signature:

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F#NPO-P0002E-US1201 DSC0-101U014318

NPO#NAU-P1558-USA:0 CUST#UMCD-2012-0289

COMBINE DECLARATION (37 CFR 1.63) FOR UTILITY OR DESIGN APPLICATION USING AN APPLICATION DATA SHEET (37 CFR 1.76) AND ASSIGNMENT

Title of Invention:

COMPLEMENTARY METAL OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTOR, METAL OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTOR AND MANUFACTURING METHOD THEREOF

As the below named inventor, I here This declaration is directed to:	by declare that:			
☑ The attached application, or	•			
☐ United States application number		filed o	_filed on,	
☐ PCT international application number		file	ed on	
The above-identified application was	s made or authorized to	be made by me.		
I believe that I am the original invent application.	or or an original joint in	ventor of a claime	ed invention in the	
I hereby acknowledge that any willfu under18 U.S.C. 1001 by fine or impr				
In consideration of the payment by	UNITED MICROEL CORP.	ECTRONICS	having a postal ac —	dress of
No.3, Li-Hsin Road 2, Science	e-Based Industrial I	Park, Hsin-Chu	ı City 300, Taiwa	n, R.O.C.
(referred to as "ASSIGNEE"below) to acknowledged, andfor other good ar			receipt of which is h	nereby
I hereby sell, assign and transfer to a the entire right, title and interest in a invention as above-identified applica invention by the above application of substitutes, or extensions thereof, an	nd to any and all impro ation and, in and to, all l r any continuations, co	vements which ar _etters Patent to k ntinuation-in-part,	e disclosed in the be obtained for said divisions, renewals,	ı
I hereby covenant that no assignment entered into which would conflict with		encumbrance has	been or will be mad	le or
I further covenant that ASSIGNEE wand documents relating to said inverknown and accessible to I and will terelated thereto and will promptly exe	ntion and said Letters P estify as to the same in	atent and legal ed any interference,	quivalents as may be litigation proceeding	е
representatives any and all papers, i maintain, issue and enforce said app equivalents thereof which may be no IN WINTNESS WHEREOF, I have h	olication, said invention ecessary or desirable to	and said Letters carry out the pro	Patent and said poses thereof.	of signing)
Note: An application data sheet (PTG inventive entity, must accompany thi				

Page 3 of 4

F#NPO-P0002E-US1201 DSC0-101U014318

Docket No NAUP1558USA

LEGAL NAME OF INVENTOR(ASSIGNOR)				
Inventor:	Shih-Hung Tsai	Date:	JAN 03 2013	
Signature:	Shick Hung Toni			

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NPO#NAU-P1558-USA:0 CUST#UMCD-2012-0289

RECORDED: 01/10/2013

F#NPO-P0002E-US1201 DSC0-101U014318

— PATENT REEL: 029608 FRAME: 0382